

EUROPEAN WORKSHOP ON PHOTOCATHODES FOR ACCELERATOR APPLICATIONS (EWPA) –ELECTRON SPIN POLARIZATION RELATED ACTIVITIES IN EUROPE

Polarized Sources and Targets Workshop

PSTP-24

Wednesday, SEP 25. 2024

Kurt Aulenbacher

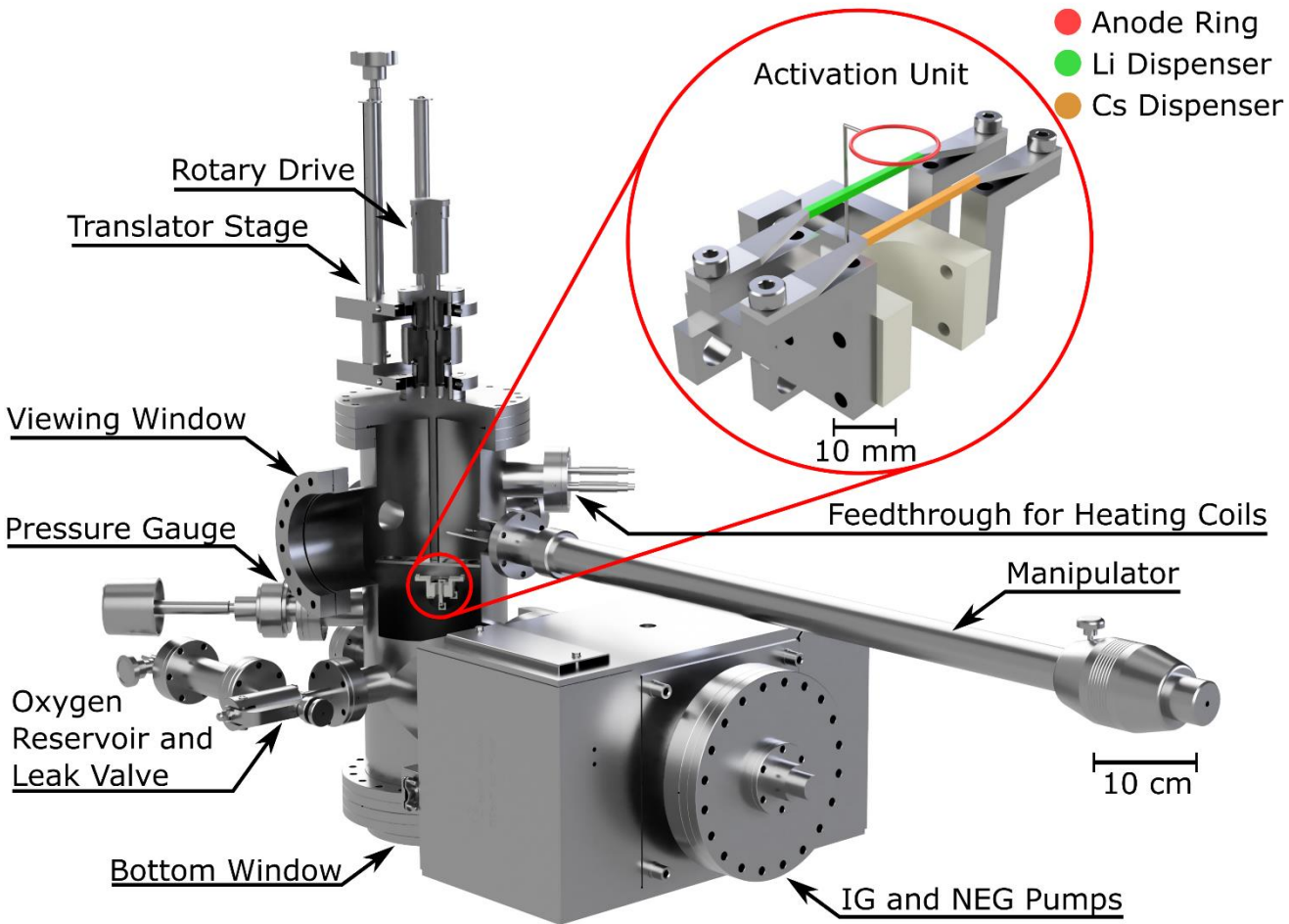
Institut für Kernphysik der Universität Mainz



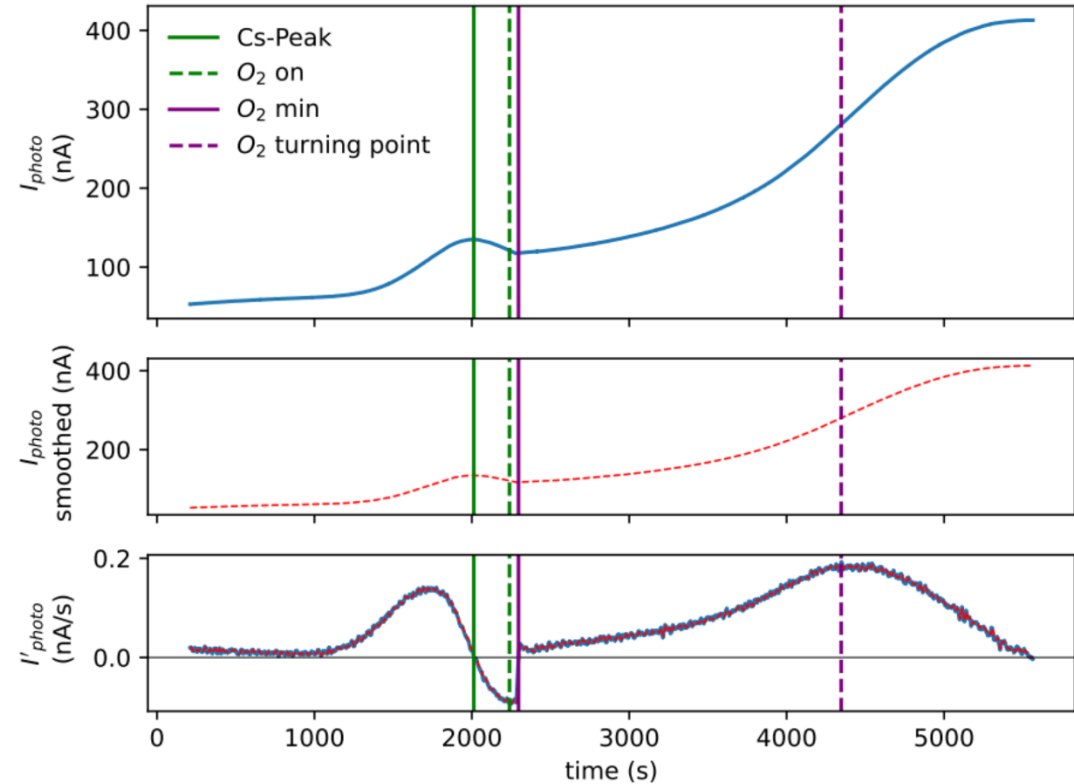
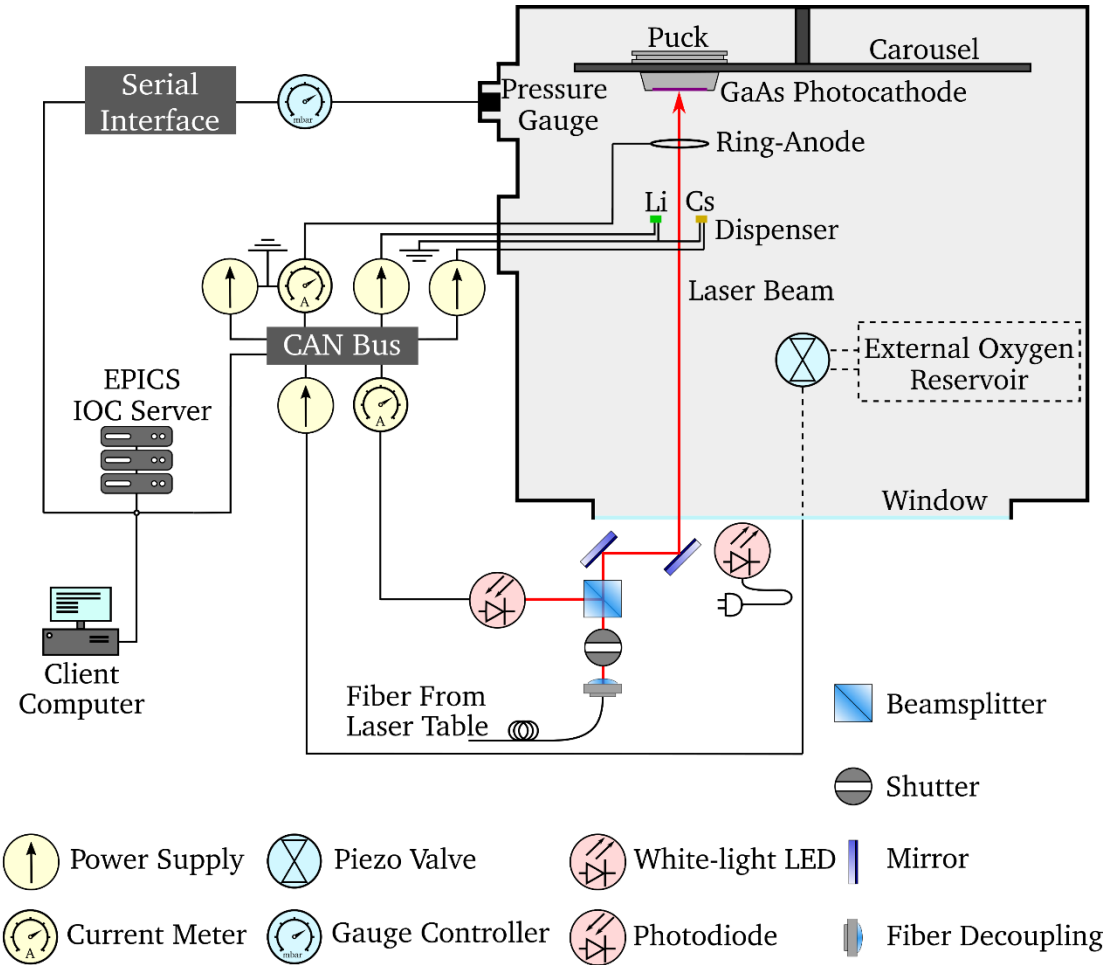
Outline-

- NEA-GaAs lifetime work at Darmstadt
- Spin polarization drift of NEA cathodes
- Sustainable photocathode supply
- Low intensity spin polarized positron sources: Mainz/Dresden/Munich
- A new polarimeter idea - the „Colliding beam Möller polarimeter“

TU-Darmstadt Activities



M. Herbert, TU-Darmstadt- Automatic activation



➔ first tests successful!

TU-Darmstadt: Lithium „assisted“ activation

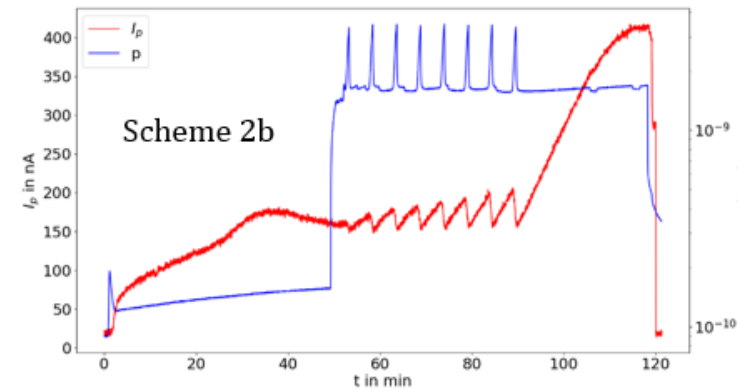
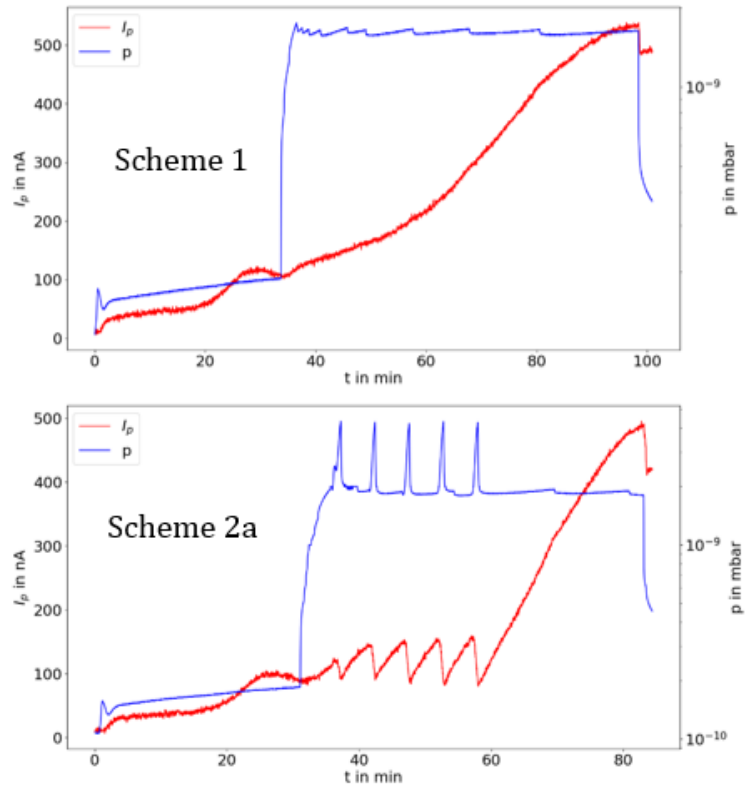
Motivation – Experimental Setup – Automated Activation – Li-enhancement – Conclusion & Outlook



TECHNISCHE
UNIVERSITÄT
DARMSTADT

Li-enhanced activation

- Goal: enhanced lifetime
- Co-De with pulsed Li, based on previous study
- Scheme 1: Cs + O₂
- Scheme 2a: Cs + O₂ + Li, 5 pulses
- Scheme 2b: Cs + O₂ + Li, 8 pulses



TU-Dar

19.09.2024

Maximilian Herbert | Institut für Kernphysik | AG Enders | EWPAA Dresden



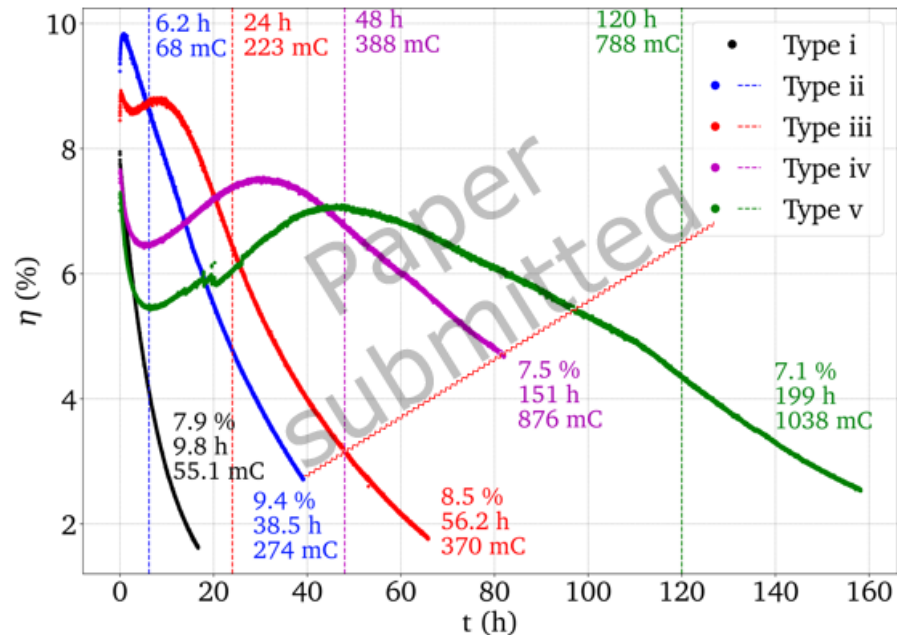
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TU-Da: Lifetime improvement

Motivation - Experimental Setup - Automated Activation - Li-enhancement - Conclusion & Outlook



Li-enhanced activation



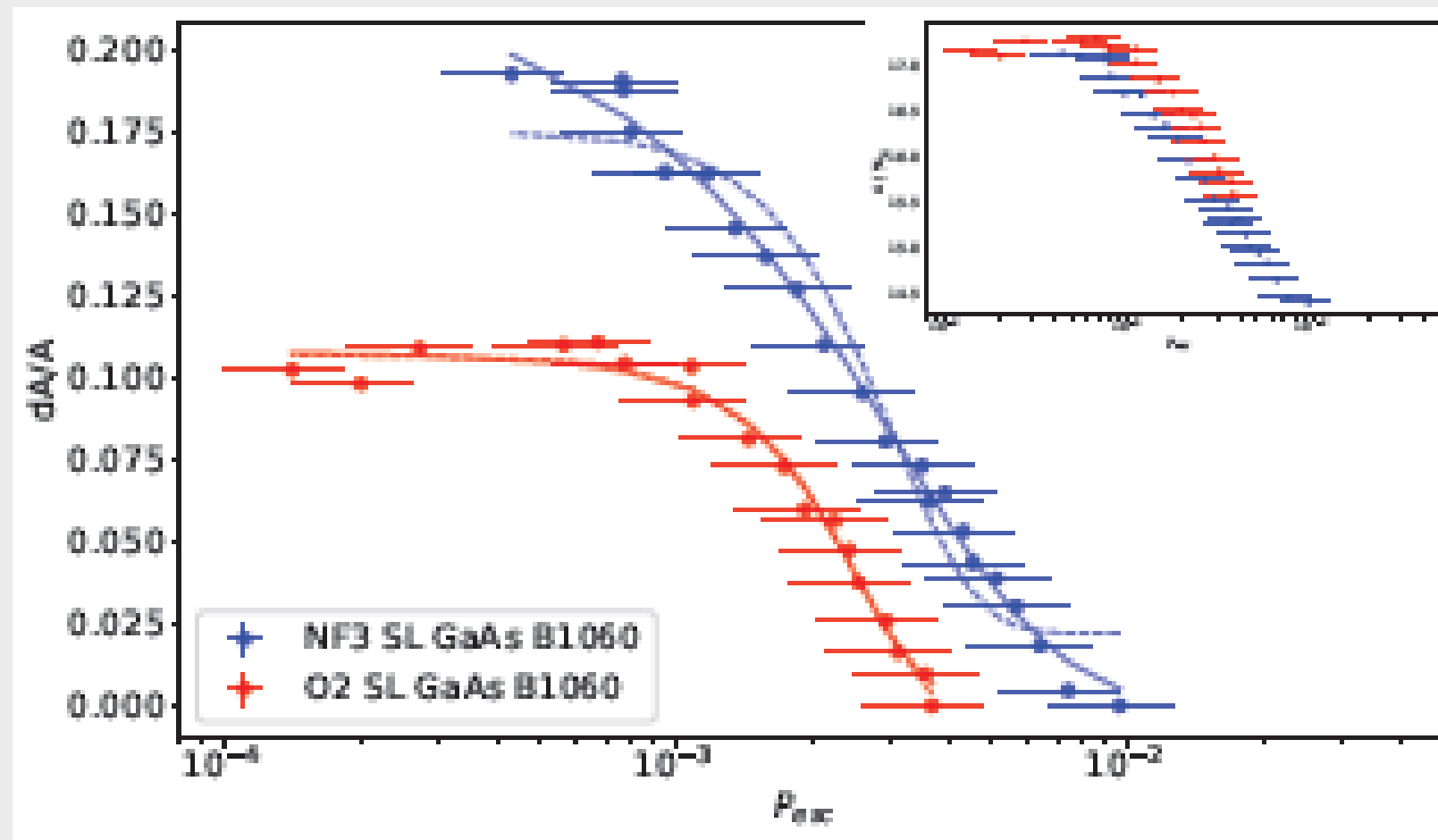
- QE & Lifetime measurements in activation chamber
- $P_{\text{laser}} = (50 \pm 5) \mu\text{W}$, $\lambda = (785 \pm 2) \text{ nm}$,
 $U_{\text{bias}} = 100 \text{ V}$
- 5 types of activations:
 - Scheme 1, no prior scheme 2
 - Scheme 1, subsequent to scheme 2a
 - Scheme 2a, subsequent to scheme 1
 - Scheme 2b, subsequent to scheme 1
 - Scheme 2b, subsequent to scheme 2b
- Effect of Li on subsequent activations observed

Significant increase in τ (up to factor 19) and $Q(\tau)$ (up to factor 16.5) observed!

Tests in DC-HV-gun upcoming!

JGU: Drift of polarization

Correlation between Asymmetry and Escape Probability



See also
Talk by J. Trieb
This conference

Positrons in Europe

1. Mainz: Channeling of 600 MeV positrons (polarization on demand)
2. Dresden HZDR: Thermal **polarized** positron source desired
3. Munich/FRM-2: Acceleration of thermalized (polarized) positrons at NEPOMUK to 1 MeV (MAMI technology, using 3d Printing of acclerator structures)
4. Mainz – target tests for CEBAF-polarized positron source

Spin polarized positrons can make use of the electron \rightarrow photon \rightarrow pair production process

This also generates spin polarized positrons by spin transfer

But will the positrons be polarized too –yes!

Principle demonstrated by the PEPPPO experiment at JLAB!

(D. Abbot et al.:

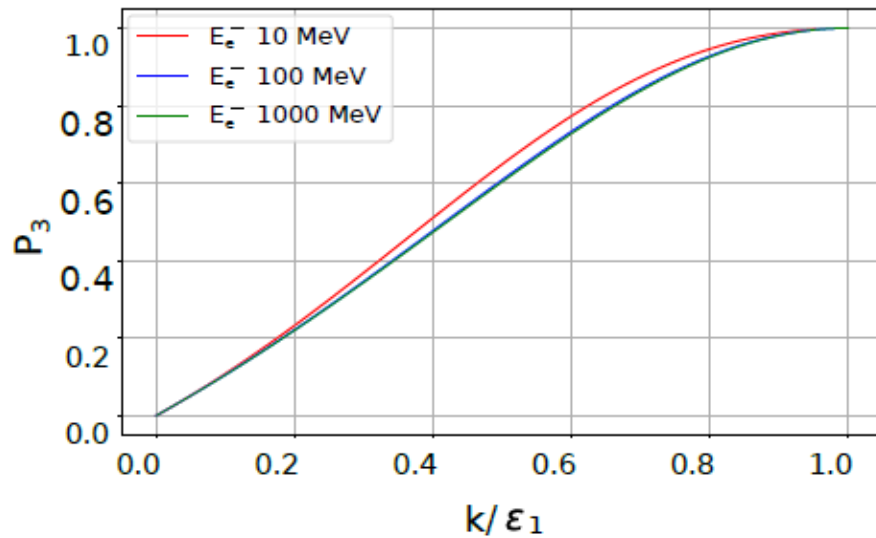
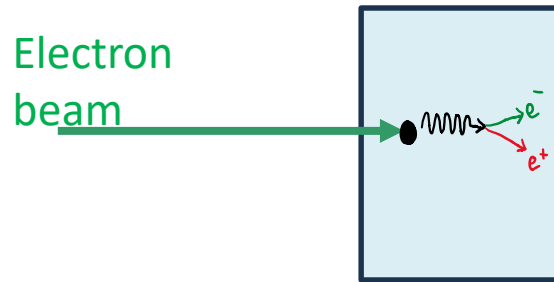
<https://link.aps.org/doi/10.1103/PhysRevLett.116.214801>)

Thick-targets:

Cross sections and multiple scattering must be taken into

Account → PhD work by S. Habet at ORSAY for JLAB

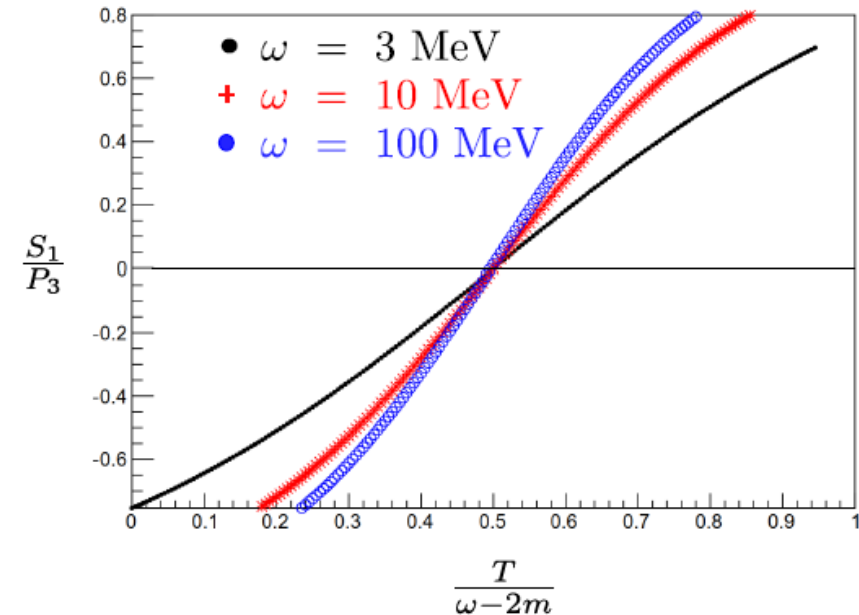
Double conversion in thin target



Transfer of electron polarization to photon circ. pol.

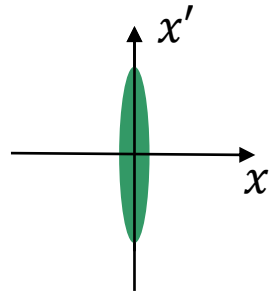
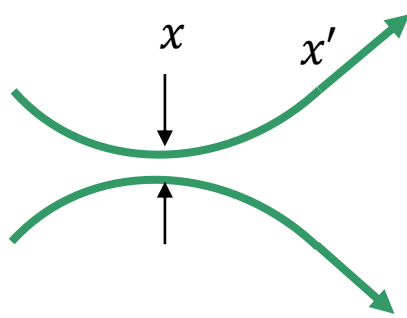
Figures after QED calculations by Olsen et al, taken from:

S. Habet: Concept of a polarized electron source for CEBAF, PhD Thesis, Université Paris-Saclay, CNRS, IJCLab, 91405, Orsay, France. (2023)



Transfer of photon circ. pol. To positron pol

Thin target: „Good“ geometrical emittance of e+ beam....



vertical

$$\begin{aligned} \text{MAMI: } \varepsilon_x &= x \cdot x' \\ &= 1 \text{ mm} \cdot \mu\text{rad} \\ &= 10 \mu\text{m} \cdot 0.1 \text{ mrad} = 1 \text{ nm} \end{aligned}$$

Emittance $\varepsilon_x = x \cdot x' = \frac{F}{\pi} = \text{const}$

Thin target for Positron production

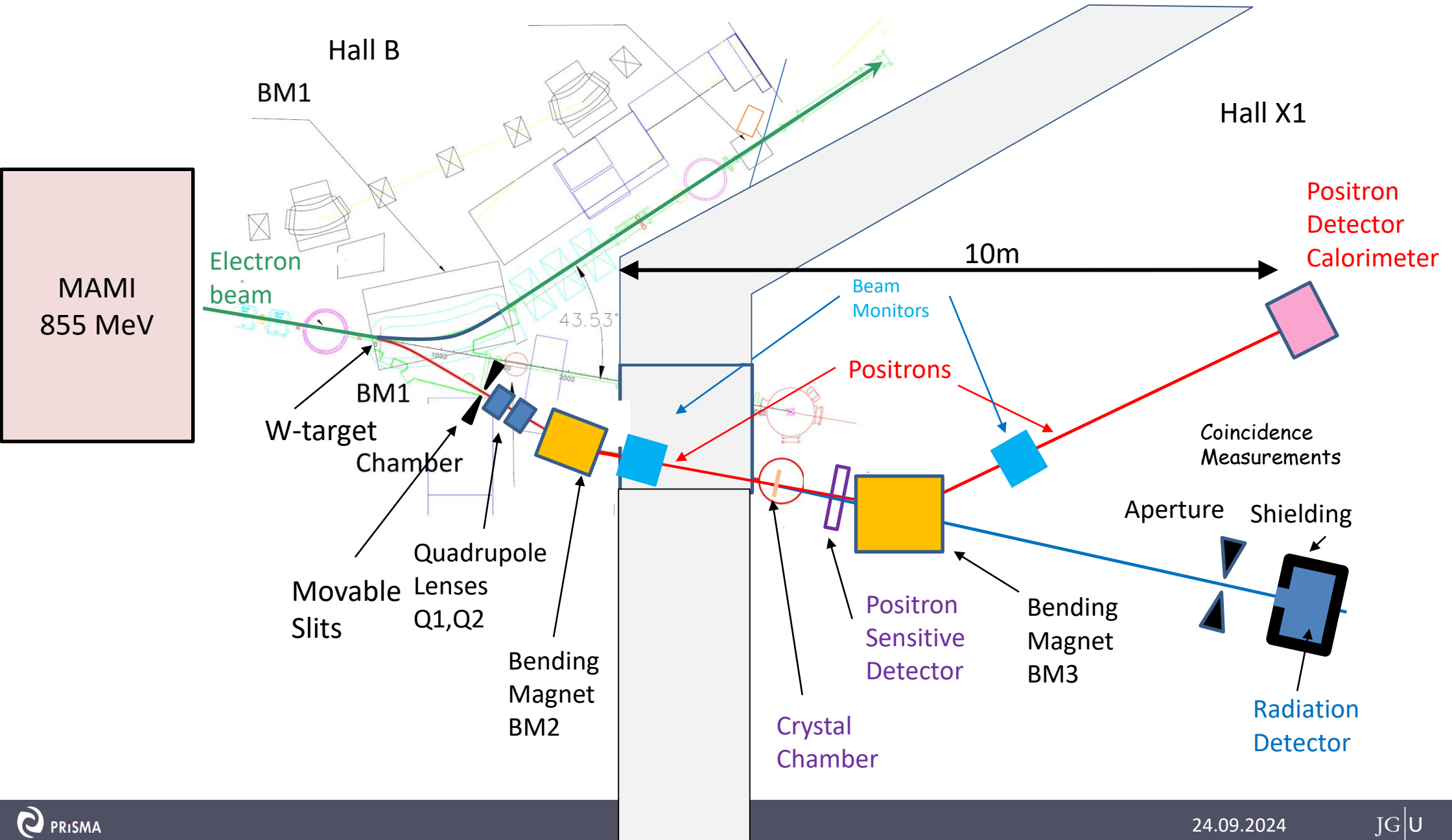
$10 \mu\text{m } W \rightarrow \text{Scattering } \sigma_S = 0.94 \text{ mrad}$

$$\sigma_p \cong \frac{1}{\gamma} = 1 \text{ mrad @500MeV}$$

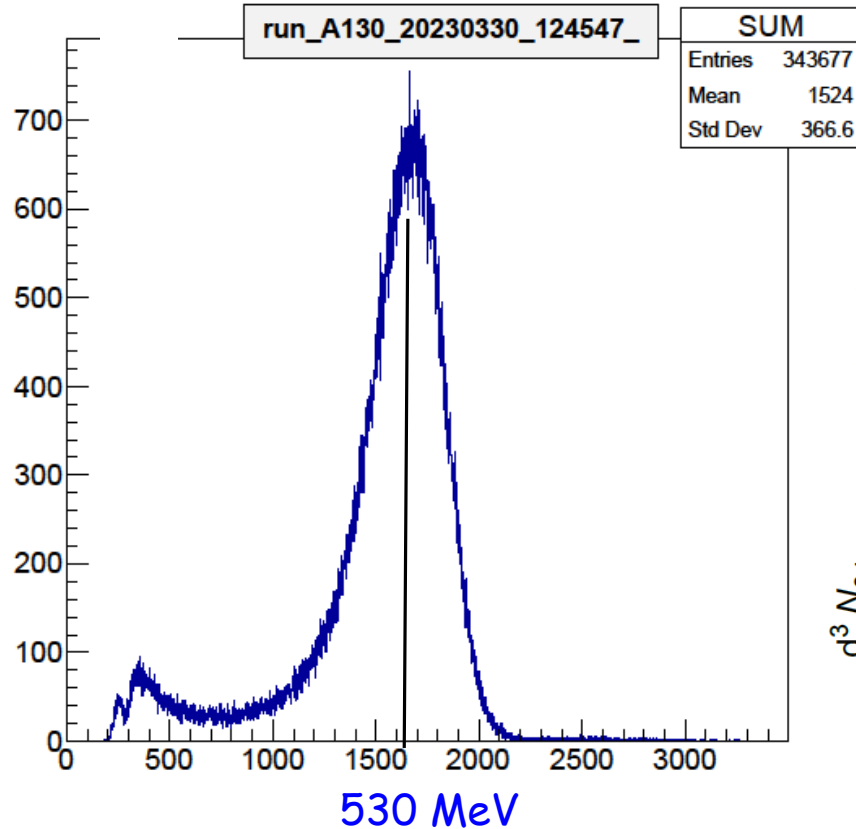
$$\varepsilon_{e^+} = 10 \mu\text{m} \cdot 1.4 \text{ mrad}$$

Emittance of Positrons: $= 1 \text{ mm} \cdot 0.014 \text{ mrad} = 14 \text{ nm}$

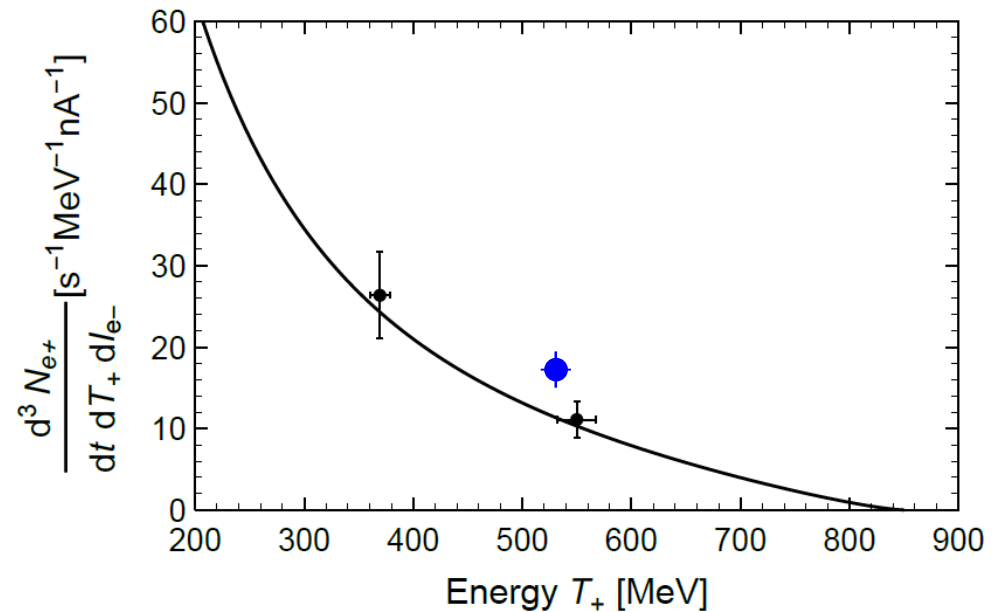
Overview Positron beam line



Production Rate



10 μm W Target
Slit width 3mm
 ~ 4.5 MeV



$$17.3 \frac{1}{\text{s} \cdot \text{nA} \cdot \text{MeV}}$$

Max. e-current (without shielding) $\sim 1 \mu\text{A}$ \rightarrow
Max. positron rate **20 kHz**

Positrons in Europe

1. Mainz: 600 MeV positron beam with high beam quality – setup completed and running
(no polarization experiment planned so far...)
2. Dresden HZDR: 250keV **polarized** positron source desired , Conversion at ~30 MeV
3. Munich/FRM-2: Acceleration of thermalized (polarized) positrons at NEPOMUK to 1 MeV (MAMI technology, using 3d Printing of accelerator structures)
4. Mainz – target tests for CEBAF-polarized positron source

Applied Research activities ask for <100kHz polarized positrons (3 Attoampere) → good beam could possibly be delivered with moderate effort (10 μ A beam) polarized current on 10 μ m W-Target

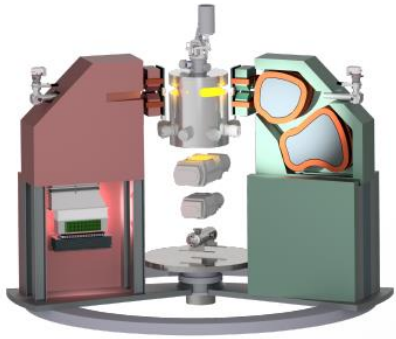
Open questions: Depolarisation by Moderator/deceleration ?

→ Mainz will support HZDR integrating polarized source into the ELBE accelerator

Establishing a sustainable supply for SL-cathodes

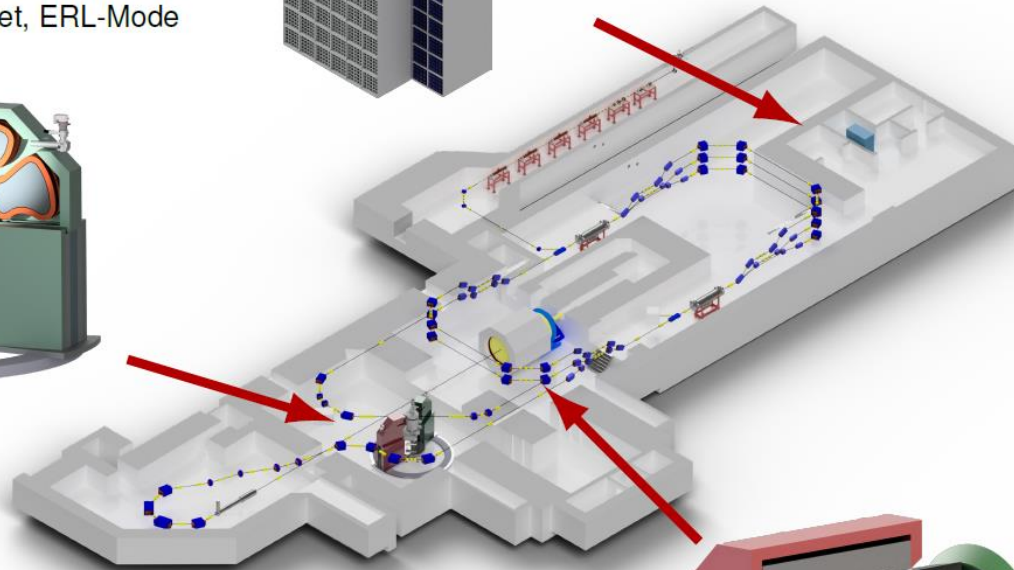
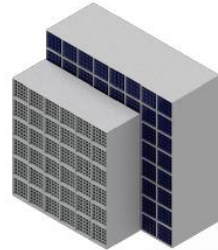
MAGIX

- High Resolution Spectrometers
- Internal Gas Target, ERL-Mode



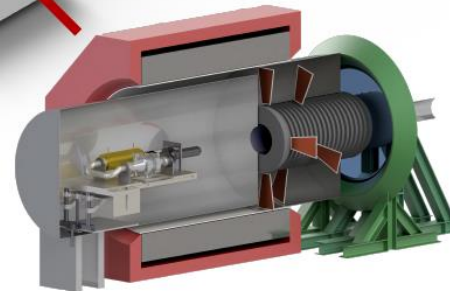
DarkMESA

- Search for Dark Sector Particles



P2

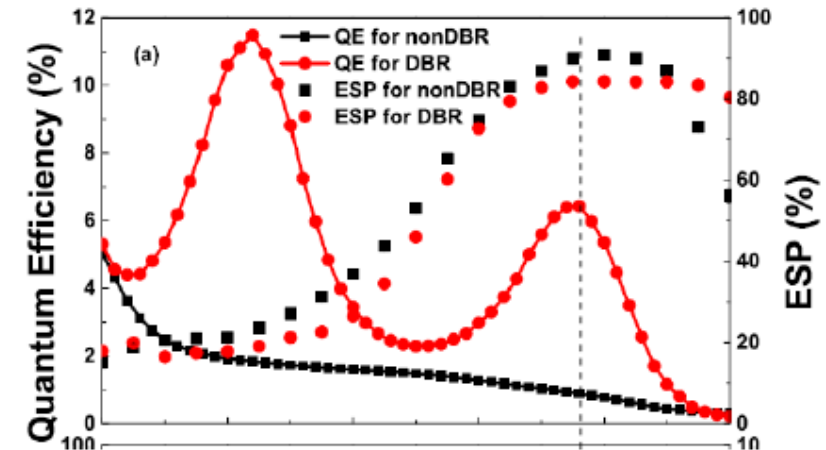
- Parity-Violating \vec{e} -scattering
- Extracted Beam (155 MeV, 150 μ A)



The MESA Project at JGU needs reliable supply of photocathodes achieving >85% polarization with QE >1% for the next decades!

State of the art Superlattice cathodes

| | | | | | |
|--|--------------------------|--------------------------------------|--|--------------------------|--------------------------------------|
| GaAs | 5 nm | $p=5 \times 10^{19} \text{ cm}^{-3}$ | GaAs | 5 nm | $p=5 \times 10^{19} \text{ cm}^{-3}$ |
| GaAs/GaAsP SL | (3.8/2.8 nm) $\times 14$ | $p=5 \times 10^{17} \text{ cm}^{-3}$ | GaAs/GaAsP SL | (3.8/2.8 nm) $\times 14$ | $p=5 \times 10^{17} \text{ cm}^{-3}$ |
| GaAsP _{0.35} | 2750 nm | $p=5 \times 10^{18} \text{ cm}^{-3}$ | GaAsP _{0.35} | 750 nm | $p=5 \times 10^{18} \text{ cm}^{-3}$ |
| Graded GaAsP _x (x = 0-0.35) | 5000 nm | $p=5 \times 10^{18} \text{ cm}^{-3}$ | GaAsP _{0.35} /AlAsP _{0.4} DBR | (54/64 nm) $\times 12$ | $p=5 \times 10^{18} \text{ cm}^{-3}$ |
| GaAs buffer | 200 nm | $p=2 \times 10^{18} \text{ cm}^{-3}$ | GaAsP _{0.35} | 2000 nm | $p=5 \times 10^{18} \text{ cm}^{-3}$ |
| p-GaAs substrate ($p>10^{18} \text{ cm}^{-3}$) | | | Graded GaAsP _x (x = 0-0.35) | | |
| | | | 5000 nm | | |
| | | | $p=5 \times 10^{18} \text{ cm}^{-3}$ | | |
| | | | GaAs buffer | | |
| | | | 200 nm | | |
| | | | $p=2 \times 10^{18} \text{ cm}^{-3}$ | | |
| | | | p-GaAs substrate ($p>10^{18} \text{ cm}^{-3}$) | | |



JLAB/SVT cooperation

Table and plot taken from: Liu et al. Appl. Phys. Lett. **109**, 252104 (2016); doi: 10.1063/1.4972180

1%QE at 780nm = 6mA/Watt!

Prepare for lifetimes effects → Present (upper) limit of charge lifetime ~200 Coulombs at MAMI corresponds to 60hours at 1mA

For currents at multi-milliampere scale DBR based superlattices are mandatory!

The issue with vendors....

1. The old vendor does not want to deliver samples any more.
2. GaAsP not very attractive for mass fabrication (contrast to the 1990 „epitaxy“ peak)
3. Handling Phosphorus difficult and blocks production
4. → an issue of „world wide“ interest. Stakeholders: Particle physicists (EIC, EICC, LHEC,..), e+ source developers ...and MAMI/MESA at Mainz.

Mainz/MESA has contacts to several national semiconductor research institutes (from the Fraunhofer and Leibniz institutes).

Production offer & services by federal lab:

Teil A - Fertigung des Puffers

Detailliertes Verfahren (Ausschreibung 3.2 a)

1. Epitaxieentwicklung auf p-leitenden GaAs-Substraten eines 5000 nm dicken Stufenpuffers (graded buffer) von GaAs hin zu GaAs_{0.65}P_{0.35}
2. inklusive Kalibrierung der Gasquellen-Regelparameter für As und P
3. inklusive Charakterisierung der Schichten mittels optischer Mikroskopie, hochauflösender Röntgenbeugung (HRXRD) und reciprocal space maps (RSM) sowie Sekundärionen-Massenspektroskopie (SIMS)
4. inklusive der Entwicklung und Analyse der in-situ-Messung der Substratkrümmung und Schichtverspannung (EZcurve) für den graded buffer
5. Epitaxieentwicklung metamorpher GaAs_{0.65}P_{0.35}-Puffer auf vorher entwickelten Stufenpuffer mit Variation der Wachstumstemperaturen für reduzierte AFM- (atomic force microscopy) Rauigkeit
6. inklusive Charakterisierung mittels Mikroskopie, AFM, EZcurve, HRXRD mit RSM
7. inklusive der Entwicklung und Analyse der in-situ-Messung der Substratkrümmung und Schichtverspannung (EZcurve) für den graded buffer
8. inklusive Charakterisierung mittels Transmissionselektronenmikroskopie (TEM) zur Bestimmung von Versetzungsdichten

The text on the left is only the number of steps required to make the buffer layer!

| | | |
|--|------------------|--------------------------------------|
| GaAs | 5 nm | $p=5 \times 10^{19} \text{ cm}^{-3}$ |
| GaAs/GaAsP SL | (3.8/2.8 nm) ×14 | $p=5 \times 10^{17} \text{ cm}^{-3}$ |
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| Graded GaAsP _x (x = 0-0.35) | 5000 nm | $p=5 \times 10^{18} \text{ cm}^{-3}$ |
| GaAs buffer | 200 nm | $p=2 \times 10^{18} \text{ cm}^{-3}$ |
| p-GaAs substrate ($p>10^{18} \text{ cm}^{-3}$) | | |

Even if the production produces non-optimal results, the information about the growth will be transferred to us!

The colliding beam online-polarimeter

Spoiler:

- Works only at source energies
- Requires very high average currents of at least $100\mu\text{A}$

The colliding beam Moller polarimeter

Since all the bunches produced by the cathode have the same polarization, the resulting experimental asymmetry of colliding bunches is:

$$A = S_{Moller} P_e^2$$

Since we have free electrons scattering and colliding head on we can calculate S_{Moller} extremely accurately, pointing at an accuracy of the extraction

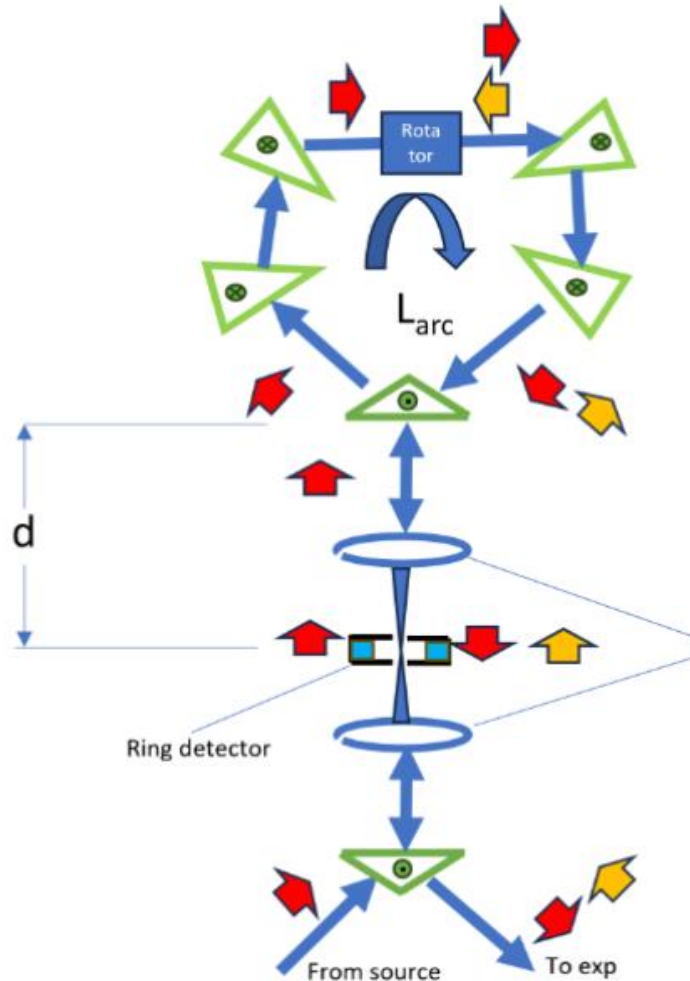
$$P_e = \sqrt{\frac{A}{S_{Moller}}}$$

in the low 10^{-3} region or even lower...

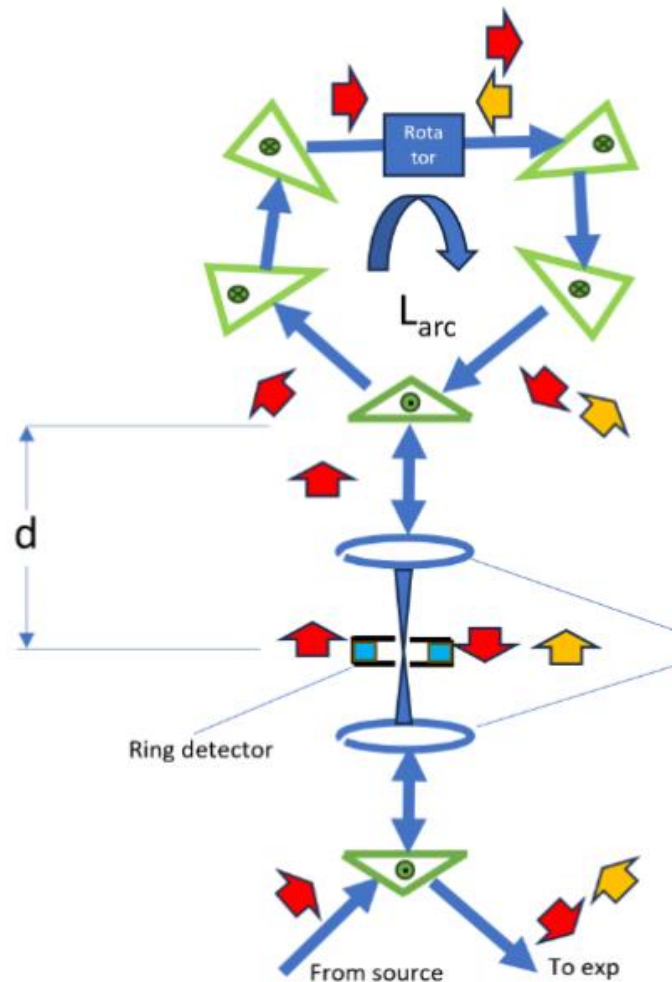
The cross section is depending on the total energy squares s (Lab frame and CM-frame are identical here)

$$\sqrt{s} = 2(E_{kin} + m_e c^2)$$

$$\frac{d\sigma}{d\Omega} = \frac{\alpha^2}{s} \frac{(3 + \cos^2\theta)^2}{\sin^4\theta}$$



The colliding beam Moller polarimeter



Luminosity:

$$L = f_{coll} \frac{N_B^2}{k + \pi r_{IP}^2} = I_{beam} \frac{N_B}{ek\pi r_{IP}^2}$$

Limited by „hourglass“ effect i.e. $\beta > l_{bunch}$
and $\beta_{IP} \varepsilon = r_{IP}^2$

TABLE 1. Rates and statistical accuracies with source beam parameters for MESA stage-2 assuming two steradian detector acceptance. The second parameter set represents online operation which requires reduction of average beam current towards a typical value for P2 by reducing the bunch collision rate.

| beam energy (kinetic) [MeV] | average current [mA] | collision rate [MHz] | beta function β_{IP} [m] | rate [Hz] | stat. accuracy after one hour [%] |
|-----------------------------|----------------------|----------------------|--------------------------------|-----------|-----------------------------------|
| 0.3 | 10 | 1300 | 0.01 | 412 | 0.06 |
| 0.3 | 0.15 | 20.3 | 0.01 | 5.9 | 0.57 |

Caveat: Spin flip and luminosity control !

Advantage: Lab-scale experiment!

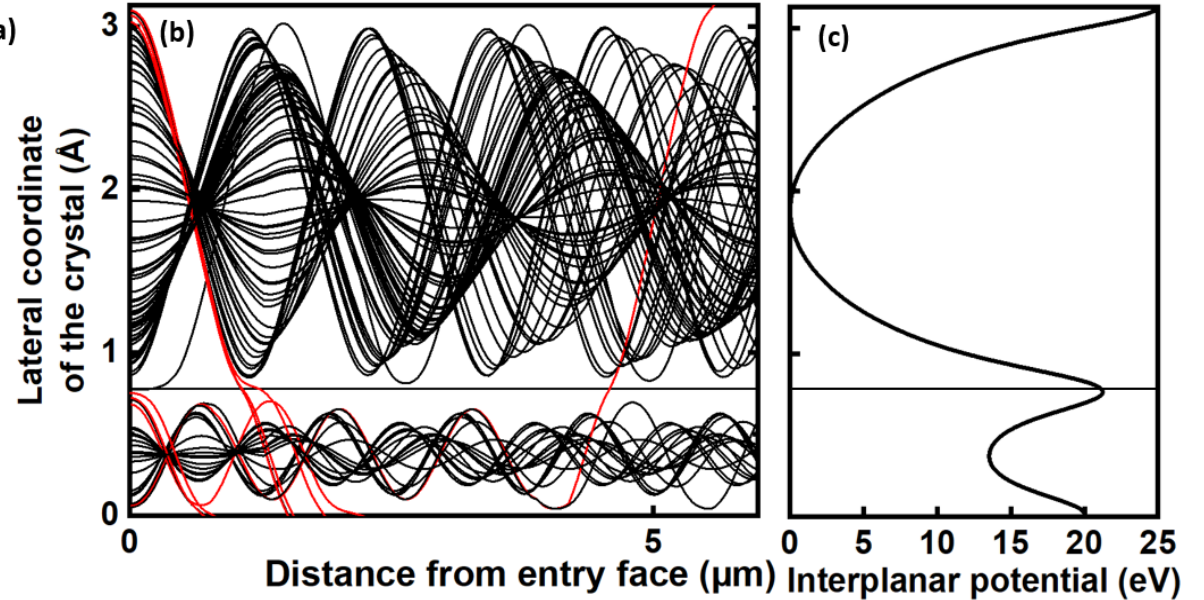
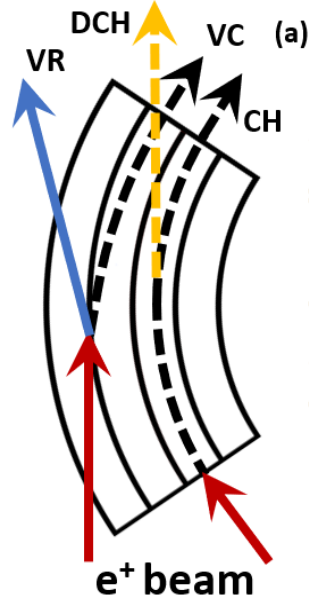
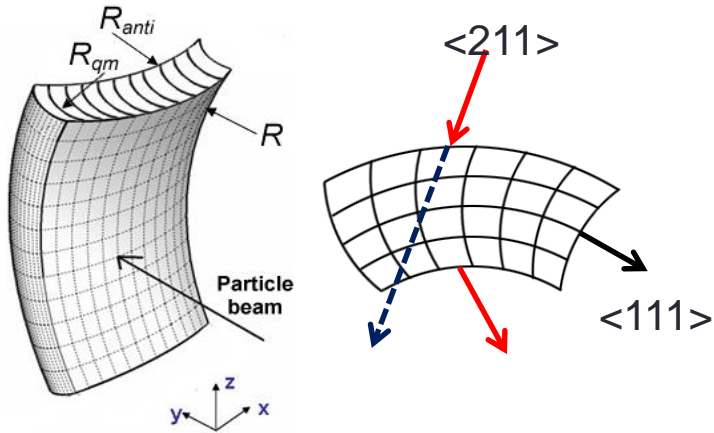
Conclusion

- Only small number of players in Europe remain
- Pol. Positrons will revive the activities
- We try to organize the sustainable delivery of cathodes for MESA
- New online-polarimeter approach is discussed at Mainz

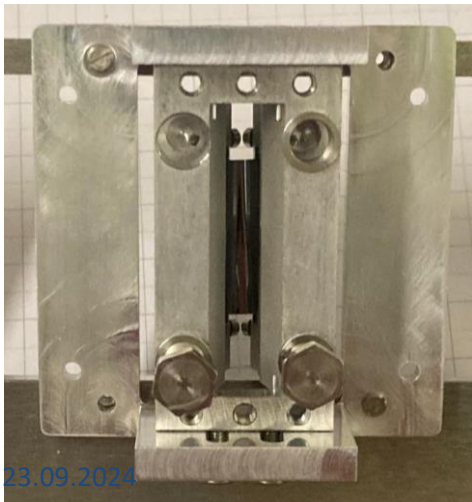
Thank you!

Spare

Beam deflection of 530 MeV positrons with mechanically bent Si crystal



Guidi, V., et al., 2009. *Journal of Physics D Applied Physics* 42(18).
 Germogli, G., *NIM B*, 2015. 355: p. 81-85

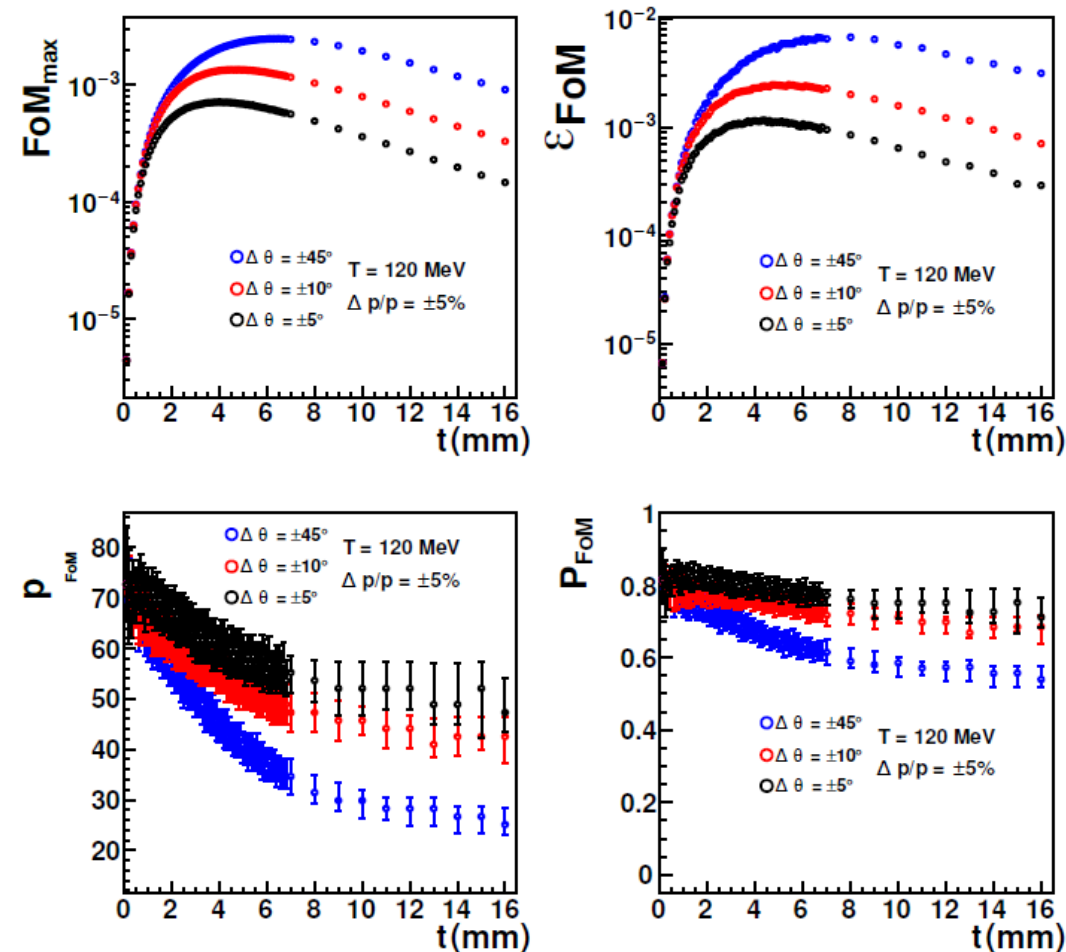


Thickness along the beam: $29.9 \pm 0.1 \mu\text{m}$ Bent planes, exploiting quasimosaic effect (111)
Bending angle: $970 \pm 10 \mu\text{rad}$

**Crystal available from a previous project @*



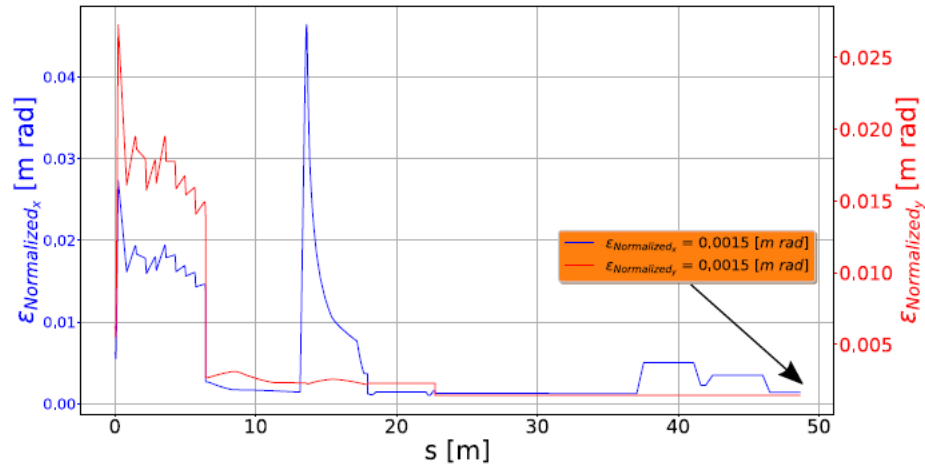
Simulations for CE⁺BAF with 126 MeV pol drive beam



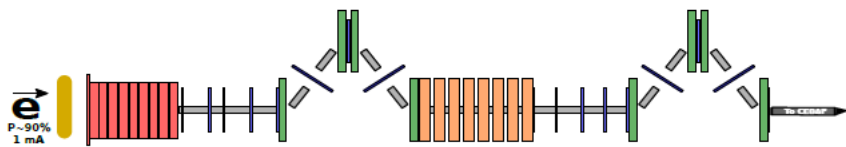
Figures/Data taken from:

S. Habet: Concept of a polarized electron source for CEBAF, PhD Thesis, Université Paris-Saclay, CNRS, IJCLab, 91405, Orsay, France. (2023)

Simulations for CE⁺BAF with 126 MeV pol drive beam



● Dipoles
● Quadrupoles
● Beam pipe



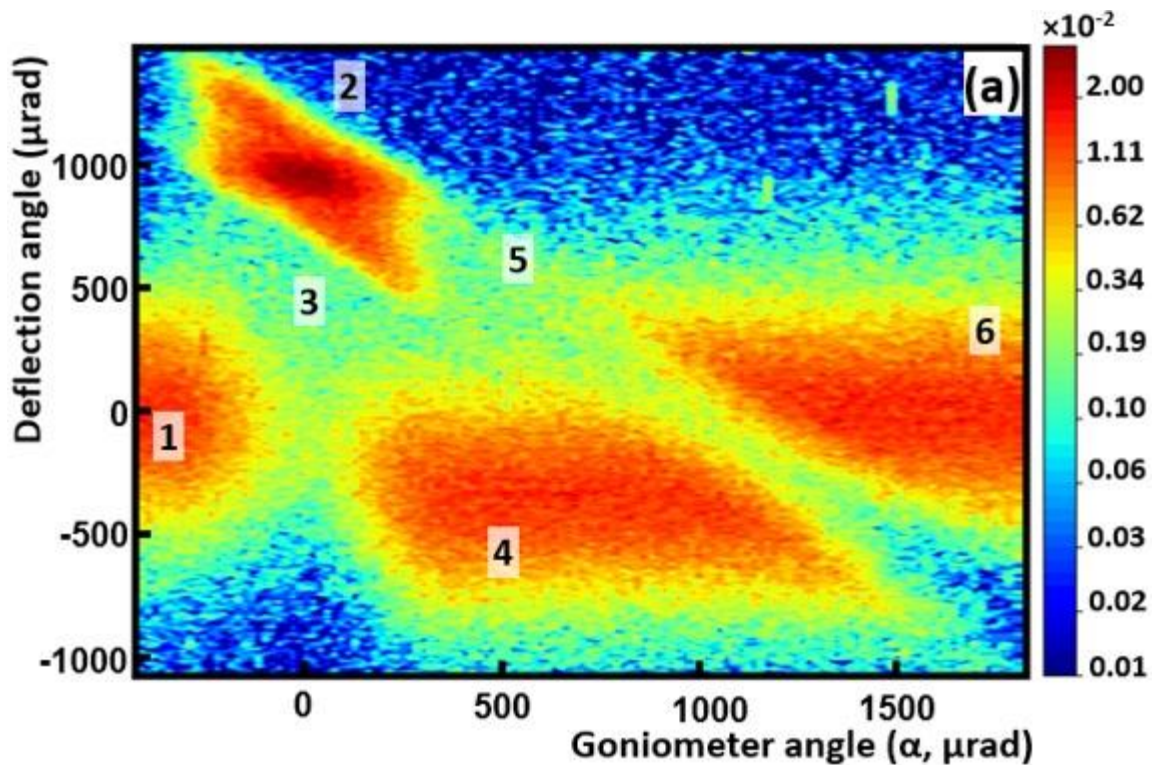
Predicted parameters:

| Predicted Parameters | |
|-------------------------------------|-----------------|
| E- beam current/Energy/Polarization | 1mA/120 MeV/0.9 |
| Positron beam current | 0.17 μ A |
| Positron Polarization | 0.65 |
| Energy width /bunch length | 0.6%/ 2ps |
| Positron normalized emittance | 1500 μ m |

Figures/Data taken from:

S. Habet: Concept of a polarized electron source for CEBAF, PhD Thesis, Université Paris-Saclay, CNRS, IJCLab, 91405, Orsay, France. (2023)

First results from e+ beam



First high-efficient deflection of sub-GeV positron worldwide !!!

Fallout in :

- Crystal-Light-Source
- Channeling based technologies
- Accelerator technologies: for beam steering, extraction, focusing..

Mazzolari, A., Backe, H., Bandiera, L., et al., (2024)
 arXiv:2404.08459

**Open access paper on arXiv
 Submitted to Phys. Rev. Lett.**

Positron Production with high power recirculating linear accelerator MAMI

MAMI: MAINZER MIKROTRON

MAMI-C – three RTM stages + „HDSM“

CW-machine

Energies: 180-1600 MeV

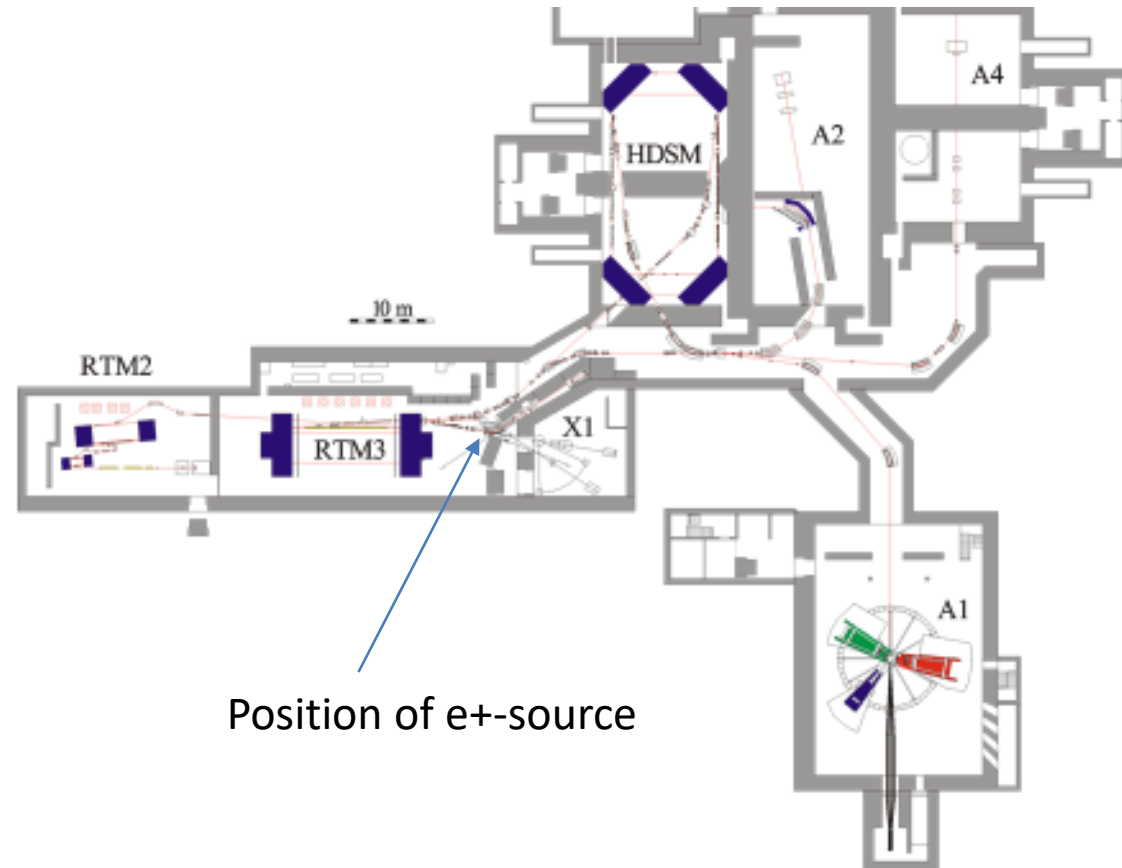
Beam current: few electrons/s – 100 μ A (150kW)

Applications:

- Electron scattering (A1)
- Tagged Photon scattering (A2)
- PV-electron scattering (A4, until 2012 \rightarrow MESA)
- Detector/materials testing
- Secondary positron beams
- Spin polarized electron beams (A1,A2,A4)

GSI-related Collaborations:

- Detector/target testing (e.g. PANDA)
- FAIR phase-0 experiment PRIMA in hall A1

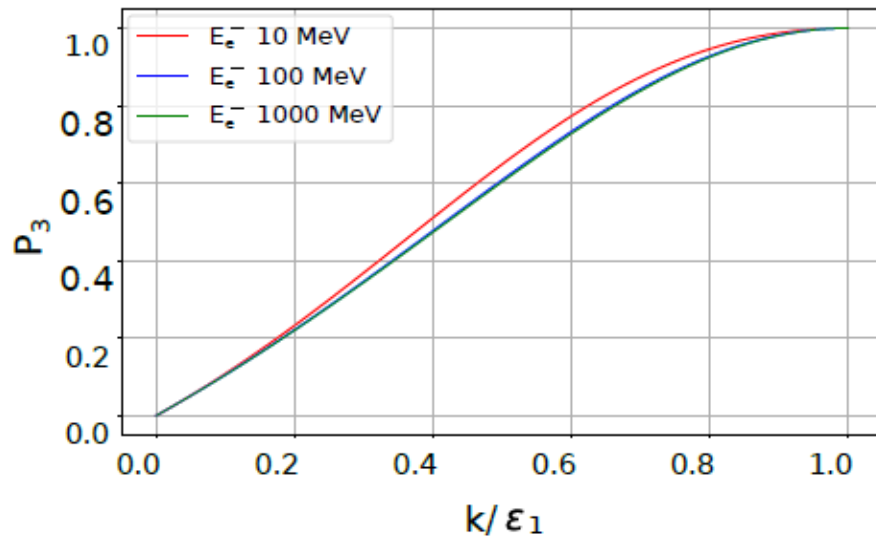
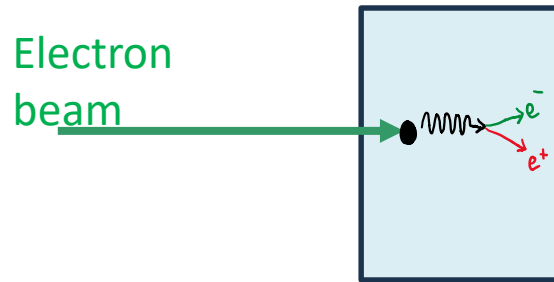


1. Why polarized positrons?

1. Particle physics: e^-/e^+ colliders (especially, but not only, linear colliders) (100 GeV scale)
2. Hadron Physics: 2 photon processes „deeply virtual Compton scattering“ (GeV scale)
3. Applied science: in particular magnetic nanostructures (eV –MEV scale)

But will the positrons be polarized too –yes!

Double conversion in thin target

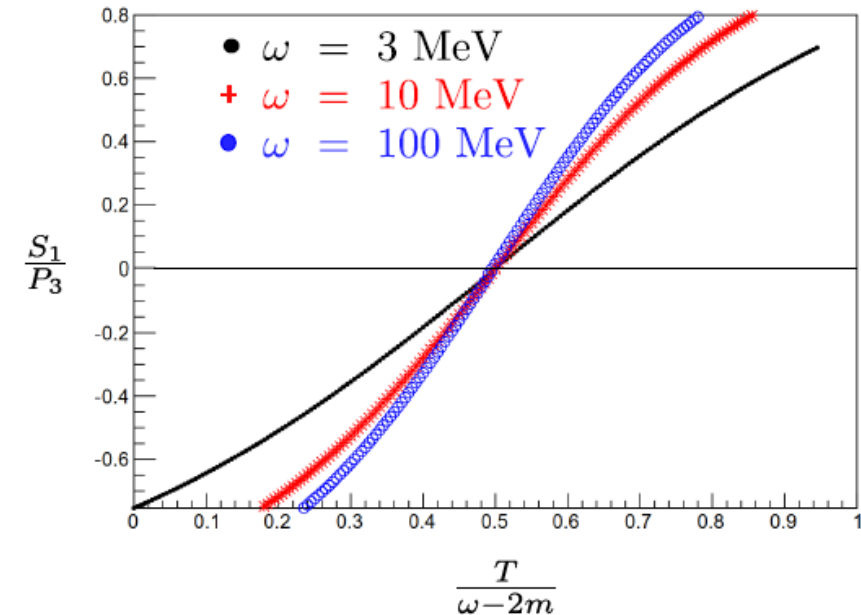


Transfer of electron polarization to photon circ. pol.

Principle first tested by SLAC/DESY collaboration for ILC in 2006.

Cross sections and multiple scattering must be taken into Account → PhD work by S. Habet at ORSAY for JLAB

Figures after QED calculations by Olsen et al, taken from:
S. Habet: Concept of a polarized electron source for CEBAF, PhD Thesis, Université Paris-Saclay, CNRS, IJCLab, 91405, Orsay, France. (2023)



Transfer of photon circ. pol. To positron pol

Low efficiency!

Based on the simulations by Habet we could assume the following requirement for the polarized electron beam with 90% Polarization at 120 MeV:

$$I_{\vec{e}^-} [mA] = 6I_{\vec{e}^+} [\mu A] \frac{1500}{\epsilon_{norm} [\mu m]}$$

Note that 1mA means 120 kW beam power on the target.

For the „rotating rim technology“ for cooling, MAMI experiments (*) at 3.5 MeV may suggest that materials can withstand such loads regarding radiation damage for very long time :

- lower energies may be better, at least to handle high beam currents....
- But high QE cathodes required because of cathode heating!

T. Lengler et al., "Characterization of radiation damages to positron source materials", in Proc. IPAC'24, Nashville, TN, May 2024, pp. 1206-1209. doi:10.18429/JACoW-IPAC2024-TUPC81

Principle of the Positron source at MAMI

